• classical Hall effect (E. Hall 1879)



• anomalous Hall effect (E. Hall, 1881)



1

Ingredients:

- magnetization (majority spin)
- spin-orbit coupling

(to couple the *majority-spin* direction to transverse motion)

Note: An example that requires no magnetization is provided by Haldane's graphene model



Theory: Intrinsic mechanism (ideal lattice without impurity)

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Hall Effect in Ferromagnetics*

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AND

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Both the unusually large magnitude and strong temperature dependence of the extraordinary Hall effect in ferromagnetic materials can be understood as effects of the spin-orbit interaction of polarized conduction electrons. It is shown that the interband matrix elements of the applied electric potential energy combine with the spin-orbit perturbation to give a current perpendicular to both the field and the magnetization. Since the net effect of the spin-orbit interaction is proportional to the extent to which the electron spins are aligned, this current is proportional to the magnetization. The magnitude of the Hall constant is equal to the square of the ordinary resistivity multiplied by functions that are not very sensitive to temperature and impurity content. The experimental results behave in such a way also.

- Linear response theory, with
- They find a transverse electron velocity (aka)

Spin-orbit coupling magnetization

structure

- anomalous velocity) that depends only on band
- Gives correct order of magnitude of ρ_{H} for Fe

also explains $\rho_{AH} \propto \rho_{I}^{2}$

Old wine in new bottle

Karplus-Luttinger theory (1954)

= Berry curvature theory (2001)

Anomalous velocity is essentially this term

$$\mathbf{v}_n(\mathbf{k}) = \frac{1}{\hbar} \frac{\partial \varepsilon_{n\mathbf{k}}}{\partial \mathbf{k}} + \frac{e}{\hbar} \mathbf{E} \times \mathbf{F}_n(\mathbf{k})$$

 $\rightarrow AHE$

$$\sigma_{xy} = \frac{e^2}{\hbar} \int_{filled} \frac{d^3k}{(2\pi)^3} \ F_z(\vec{k})$$



With this mechanism working, it's possible to have Quantum AHE (in 2D)

Experimental Observation of the Quantum Anomalous Hall Effect in a Magnetic Topological Insulator

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Reports on Quantum anomalous Hall effect

- Bi_2Te_3 theory (Yu et al, Science 2010)
- Bi₂Te₃ experiment (Chang et al, Nat Material 2015)
- manganese bismuth telluride (MnBi₂Te₄) (Deng et al, Science 2020)
- Twisted bilayer graphene (Serlin et al, Science 2020) **Orbital magnetism**
- MoTe₂/WSe₂ heterobilayers (Li et al, Nature 2021)
- $Cr_{1-x}(Bi_{1-y}Sb_y)_{2-x}Te_3$ (Okazaki et al, Nat Phys 2022)
- Twisted Bilayer MoTe₂ (Cai et al, Nature 2023)

. . .





a precision of 10 parts per billion (at mK)

Quantum anomalous Hall effectA. Qi-Wu-Zhang modelB. Edge state in Qi-Wu-Zhang model

Engineering a topological band by level crossing (Qi-Wu-Zhang model, 2006; Yu et al, Science 2010)



Using 2D surface states of magnetic topological insulator

A. Qi-Wu-Zhang model - a toy model of QAHE (2006)

$$H(\mathbf{k}) = H_0 + H_m + H_{so}, \tag{1.1}$$
$$H_0 = \varepsilon_0(\mathbf{k}) +$$

$$t \begin{pmatrix} 2 - \cos k_x a - \cos k_y a & 0 \\ 0 & -(2 - \cos k_x a - \cos k_y a) \end{pmatrix},$$
$$H_m = m \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix},$$
$$H_{so} = \lambda \begin{pmatrix} 0 & \sin k_x a - i \sin k_y a \\ \sin k_x a + i \sin k_y a & 0 \end{pmatrix}.$$

Can be realized using ultracold fermions, see Liang et al, Phys Rev Res 2023

$$\mathsf{H}(\mathbf{k}) = \varepsilon_0(\mathbf{k}) + \mathbf{h}(\mathbf{k}) \cdot \boldsymbol{\sigma}, \qquad (1.2)$$

where

$$\mathbf{h}(\mathbf{k}) = \left(\lambda \sin k_x a, \lambda \sin k_y a, m + t \sum_{j=1}^2 (1 - \cos k_j a)\right).$$

 $\varepsilon_{\pm}(\mathbf{k}) = \varepsilon_0(\mathbf{k}) \pm |\mathbf{h}(\mathbf{k})|$

Band gap could close at

$$\mathbf{k}_{0} = 0 \rightarrow \varepsilon_{\pm}(\mathbf{k}_{0}) = \varepsilon_{0} \pm m,$$

$$\mathbf{k}_{0} = (\pi, 0), (0, \pi) \rightarrow \varepsilon_{\pm}(\mathbf{k}_{0}) = \varepsilon_{0} \pm |m + 2|,$$

$$\mathbf{k}_{0} = (\pi, \pi) \rightarrow \varepsilon_{\pm}(\mathbf{k}_{0}) = \varepsilon_{0} \pm |m + 4|.$$



Hint of topology from the distribution of of $h_z(\mathbf{k})$:

1) m > 0: $h_z(\mathbf{k}) > 0$ over the whole BZ. 2) -2 < m < 0: $h_z(\mathbf{k}) < 0$ near $\mathbf{k} = 0$. 3) -4 < m < -2: $h_z(\mathbf{k}) > 0$ near $\mathbf{k} = (\pi, \pi)$ (and its equivalent points). 4) m < -4: $H_z(\mathbf{k}) < 0$ over the whole BZ.



Berrv curvature of

Berry curvature
of 2-band model

$$F_{z}^{\pm}(\mathbf{k}) = \mp \frac{1}{2h^{3}}\mathbf{h} \cdot \frac{\partial \mathbf{h}}{\partial k_{x}} \times \frac{\partial \mathbf{h}}{\partial k_{y}}.$$
Pf: $H\left(\vec{k}\right)\left|\vec{h},\pm\right\rangle = \varepsilon_{\pm}\left|\vec{h},\pm\right\rangle$

$$F_{z}^{\pm}(\mathbf{k}) = \frac{\partial A_{y}^{\pm}}{\partial k_{x}} - \frac{\partial A_{x}^{\pm}}{\partial k_{y}}$$
Berry connection
 $A_{\ell}^{\pm}(\mathbf{k}) = i\langle\mathbf{h},\pm|\frac{\partial}{\partial k_{\ell}}|\mathbf{h},\pm\rangle$

$$= \frac{\partial h_{\alpha}}{\partial k_{\ell}}i\langle\mathbf{h},\pm|\frac{\partial}{\partial h_{\alpha}}|\mathbf{h},\pm\rangle$$

$$= \frac{\partial h_{\alpha}}{\partial k_{\ell}}a_{\alpha}^{\pm}(\mathbf{h}),$$

$$a_{\alpha}^{\pm}\left(\vec{h}\right) = i\langle\vec{h},\pm\left|\frac{\partial}{\partial h_{\alpha}}\right|\vec{h},\pm\rangle$$

$$F_{z}^{\pm}(\mathbf{k}) = \frac{\partial A_{y}^{\pm}}{\partial k_{x}} - \frac{\partial A_{x}^{\pm}}{\partial k_{y}}$$

$$= \frac{\partial A_{x}}{\partial k_{x}}\left(\frac{\partial h_{\beta}}{\partial k_{y}}a_{\beta}^{\pm}\right) - \frac{\partial}{\partial k_{y}}\left(\frac{\partial h_{\alpha}}{\partial k_{x}}a_{\alpha}^{\pm}\right)$$

$$= \frac{\partial h_{\alpha}}{\partial k_{\ell}}\partial k_{\ell}(\mathbf{h},\pm|\frac{\partial}{\partial h_{\alpha}}|\mathbf{h},\pm\rangle$$

$$= \frac{\partial h_{\alpha}}{\partial k_{\ell}}\frac{\partial h_{\beta}}{\partial k_{y}}\varepsilon_{\alpha\beta\gamma}f_{\gamma}^{\pm}$$

$$= \frac{\partial h_{\alpha}}{\partial k_{\ell}}a_{\alpha}^{\pm}(\mathbf{h}),$$

$$= \pm \frac{1}{2h^{3}}\mathbf{h}\cdot\frac{\partial \mathbf{h}}{\partial k_{x}}\times\frac{\partial \mathbf{h}}{\partial k_{y}},$$

$$= \ \mp \frac{1}{2h^3} \mathbf{h} \cdot \frac{\partial \mathbf{h}}{\partial k_x} \times \frac{\partial \mathbf{h}}{\partial k_y},$$

Ch 2
$$\mathbf{F}_{\pm}(\mathbf{B}) = \nabla_{\mathbf{B}} \times \mathbf{A}_{\pm}(\mathbf{B}) = \mp \frac{1}{2} \frac{\hat{B}}{B^2}$$

 $\Rightarrow f_{\gamma}^{\pm} = \mp h_{\gamma}/2h^3$

$$\overset{h(k)}{\underset{BZ}{\longrightarrow}} f_{\gamma}^{\pm} = \mp h_{\gamma}/2h^3$$



Figs. From Asboth et al, A short course on TI

Hall conductivity from the valence band



Bulk-edge correspondence

B. Edge state in Qi-Wu-Zhang model

Numerical calculation based on lattice QWZ model



Figs. From Asboth et al, A short course on TI